

## NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE8295AG uses advanced trench technology and design to provide excellent  $R_{\text{DS}(\text{ON})}$  with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.

### **Application**

- Power switching application
- Hard switched and High frequency circuits
- Uninterruptible power supply

#### **General Features**

- $V_{DS} = 82V, I_D = 95A$  $R_{DS(ON)} < 7.0 \text{ m}\Omega$  @  $V_{GS} = 10V$  (Typ:6mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Special designed for convertors and power controls
- 150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

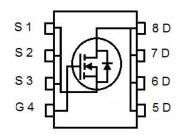
### **DFN 5X6**





Top View

**Bottom View** 



**Schematic Diagram** 

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE8295AG	NCE8295AG	DFN5X6-8L	_	_	-

## Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	82	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	ID	95	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100°C)	67	Α
Pulsed Drain Current	I <sub>DM</sub>	320	Α
Maximum Power Dissipation	P <sub>D</sub>	140	W
Derating factor		1.12	W/℃
Single pulse avalanche energy (Note 5)	Eas	480	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	$^{\circ}$

### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case <sup>(Note 2)</sup>	Rejc	0.89	°C/W
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# Electrical Characteristics (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	82	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =82V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	•					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	2	2.9	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	6	7.0	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	-	50	-	S
Dynamic Characteristics (Note4)	•					
Input Capacitance	C <sub>lss</sub>	1/ 40)/1/ 0)/	-	5633	-	PF
Output Capacitance	Coss	$V_{DS}$ =40V, $V_{GS}$ =0V,	-	268	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	226	-	PF
Switching Characteristics (Note 4)	1			,		
Turn-on Delay Time	t <sub>d(on)</sub>		-	18	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =40V, $R_L$ =15 $\Omega$	-	12	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_G=2.5\Omega, V_{GS}=10V$	-	56	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS
Total Gate Charge	Qg	)/ 40)/I 50A	-	109.3	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =40V, $I_{D}$ =50A,	-	35.1	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	25.8	-	nC
Drain-Source Diode Characteristics	'		'	'		
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =95A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	95	Α
Reverse Recovery Time	t <sub>rr</sub>	Tj=25°C,I⊧=95A	-		37	nS
Reverse Recovery Charge	Qrr	di/dt=100A/µs <sup>(Note3)</sup>	-		58	nC

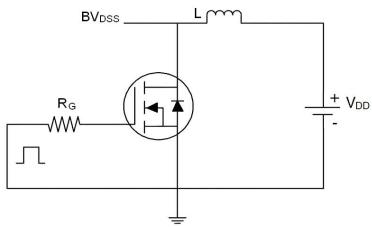
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V<sub>DD</sub>=40V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

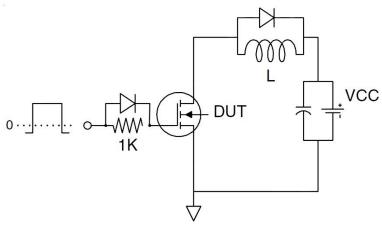


# **Test Circuit**

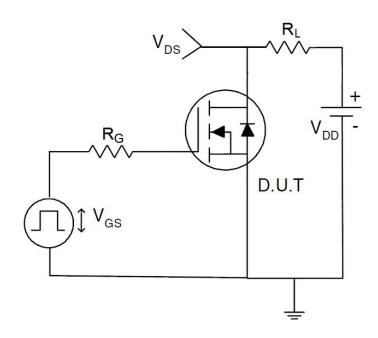
## 1) Eas Test Circuits



# 2) Gate Charge Test Circuit

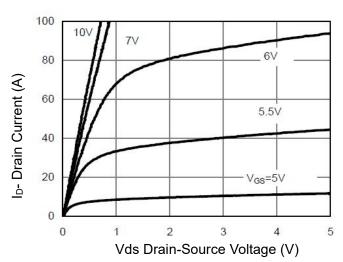


# 3) Switch Time Test Circuit

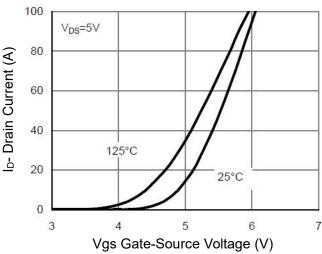




## Typical Electrical and Thermal Characteristics (Curves



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

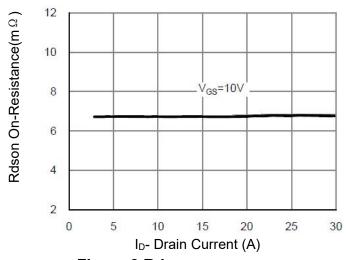


Figure 3 Rdson- Drain Current

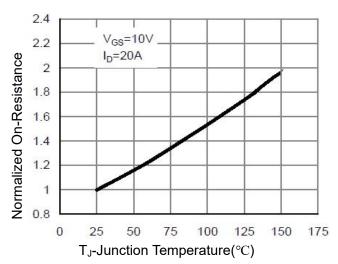


Figure 4 Rdson-Junction Temperature

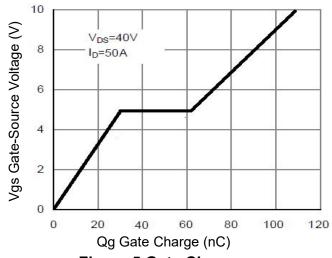


Figure 5 Gate Charge

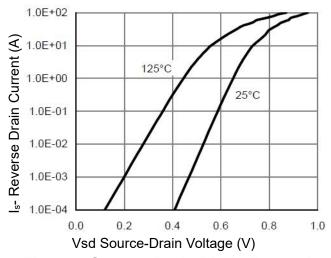


Figure 6 Source- Drain Diode Forward



1000.0

100.0

10.0

1.0

0.1

0.0

0.01

0.1

limited

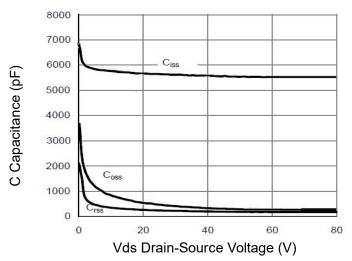
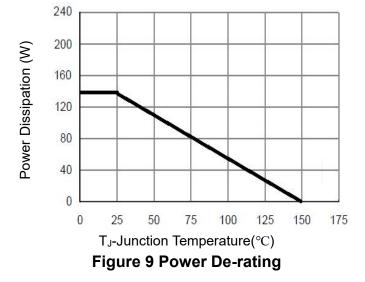


Figure 7 Capacitance vs Vds



10µs 100μs T<sub>J(Max)</sub>=175°C T<sub>C</sub>=25°C 10 100 1 1000 Vds Drain-Source Voltage (V)

Figure 8 Safe Operation Area

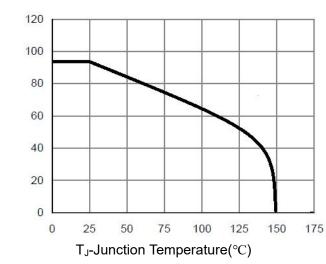
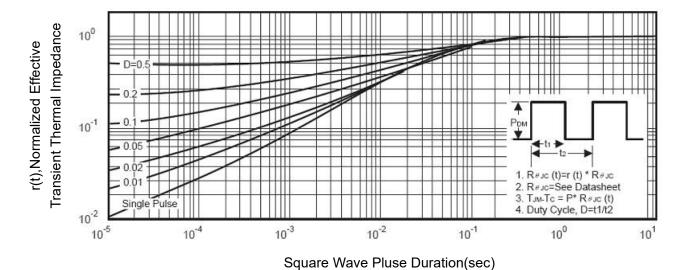


Figure 10 ID Current De-rating

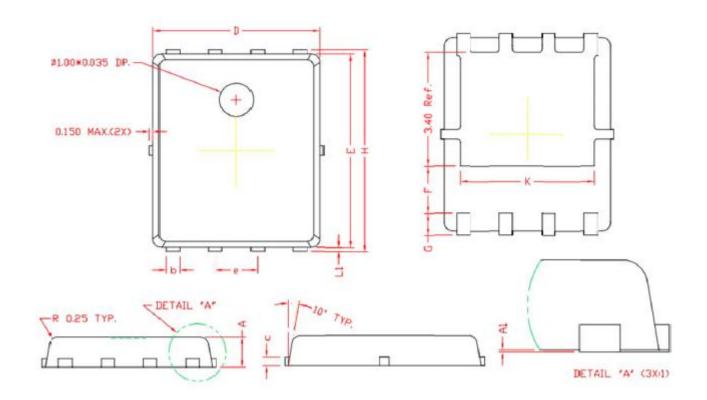


Ip- Drain Current (A)

**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **DFN5X6-8L Package Information**



## COMMON DIMENSIONS

# (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX		
A	0.80	0.90	1.00		
A1	0.00	0.03	0.05		
b	0.35	0.49			
c	0. 254 REF.				
D	4.90	5.00	5.10		
F	1				
Е	5. 70	5. 80	5. 90		
е	1. 27 BSC.				
Н	5. 95	6.08	6. 20		
L1	0.10	0. 14	0. 18		
G	G 0. 60 REF. K 4. 00 REF.				
K					



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